

W34SF4C

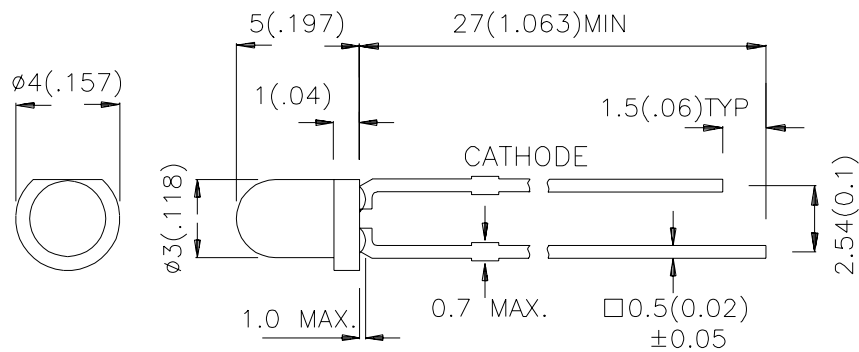
Features

- MECHANICALLY AND SPECTRALLY MATCHED TO THE L32P3C PHOTOTRANSISTOR.
- WATER CLEAR LENS AVAILABLE HIGH POWER OUTPUT.

Description

SF4 Made with Gallium Aluminum Arsenide Infrared Emitting diodes.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Po (mW/sr) @20mA*50mA		Viewing Angle
			Min.	Typ.	θ1/2
W34SF4C	GaAlAs	WATER CLEAR	1.6	4	50°
			*4	*20	50°

Notes:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
2. * Luminous intensity with asterisk is measured at 50mA.

Electrical / Optical Characteristics at T_A=25°C

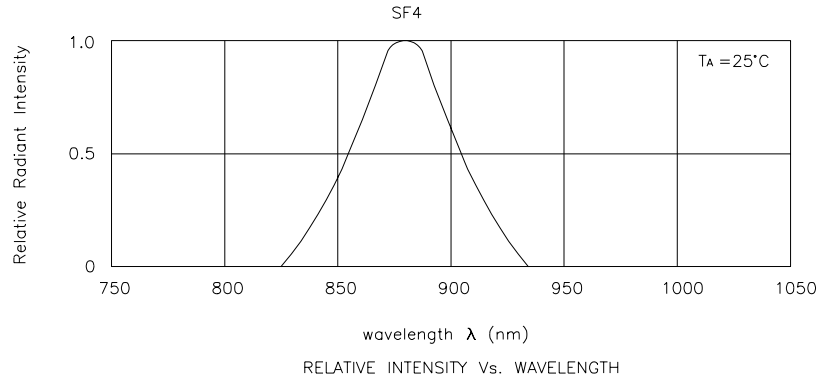
Parameter	P/N	Symbol	Typ.	Max.	Unit	Condition
Forward Voltage	SF4	V _F	1.3	1.6	V	I _F =20mA
Reverse Current	SF4	I _R	-	10	uA	V _R =5V
Capacitance	SF4	C	90	-	pF	V _F =0V; f=1MHz
Wavelength at peak emission	SF4	λ _P	880	-	nm	I _F =20mA
Spectral line half-width	SF4	Δλ 1/2	50	-	nm	I _F =20mA

Absolute Maximum Ratings at T_A=25°C

Item	Symbol	SF4	Units
Power Dissipation	P _T	100	mW
Forward Current	I _F	50	mA
Peak Forward Current[1]	i _{FS}	1.2	A
Reverse Voltage	V _R	5	V
Operating Temperature	T _A	-40~ +85	°C
Storage Temperature	T _{STG}	-40~ +85	°C
Lead Solder Temperature [2]	260°C For 5 Seconds		

Notes:

1. 1/100 Duty Cycle, 10us Pulse Width.
2. 2mm below package base.



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